



### 2DC4617Q/R/S

#### **50V NPN SMALL SIGNAL TRANSISTOR IN SOT523**

#### **Features**

- BV<sub>CEO</sub> > 50V
- I<sub>C</sub> = 150mA High Collector Current
- Ultra-Small Surface Mount Package
- Complementary PNP Type Available (2DA1774Q/R/S)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

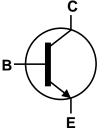
#### **Mechanical Data**

- Case: SOT523
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ©3
- Weight: 0.002 grams (Approximate)

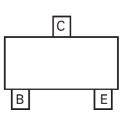


SOT523

Top View



**Device Symbol** 



Pin-Out Top View

#### Ordering Information (Note 4)

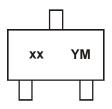
Product	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
2DC4617Q-7-F	Active	AEC-Q101	8D	7	8	3000
2DC4617R-7-F	Active	AEC-Q101	8E	7	8	3000
2DC4617S-7-F	Active	AEC-Q101	8F	7	8	3000

 EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, see http://www.diodes.com/products/packages.html.

## **Marking Information**



 $\begin{array}{l} xx = \mbox{Product Type Marking Code} \\ YM = \mbox{Date Code Marking} \\ Y \mbox{ or } \overline{Y} = \mbox{Year (ex: F = 2018)} \\ M \mbox{ or } \overline{M} = \mbox{Month (ex: 9 = September)} \end{array}$ 

Date Code Key

Notes:

Year	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	F	G	Н		J	K	L	М	Ν	0	Р	Q	R	S
Month	Jan	Feb	Ma	ar /	Apr	Мау	Jun	Jul	Aug	Se	p (	Oct	Nov	Dec
Code	1	2	3		4	5	6	7	8	9		0	Ν	D



# Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	60	V
Collector-Emitter Voltage	V <sub>CEO</sub>	50	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Collector Current—Continuous (Note 5)	I <sub>C</sub>	150	mA

# Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5) $T_A = 25^{\circ}C$	PD	150	mW
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>ØJA</sub>	833	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

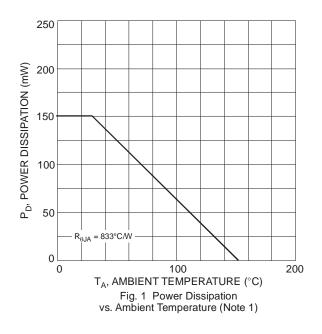
### ESD Ratings (Note 6)

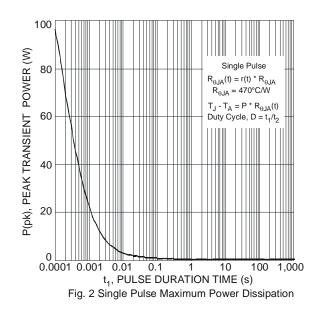
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge—Human Body Model	ESD HBM	4000	V	ЗA
Electrostatic Discharge—Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the collector lead, on a minimum recommended pad layout of 1oz copper on a single-sided 1.6mm FR4 PCB. Device is measured under still air conditions whilst operating in a steady-state.

6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

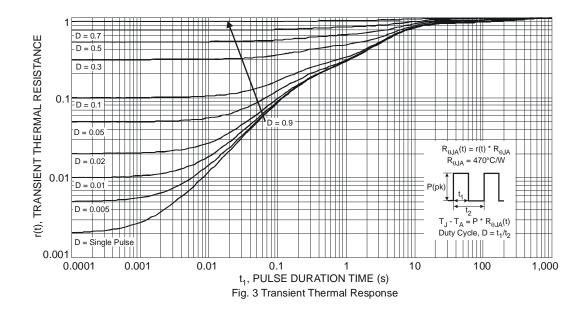
## Thermal Characteristics and Derating Information







# Thermal Characteristics and Derating Information (continued)



# Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

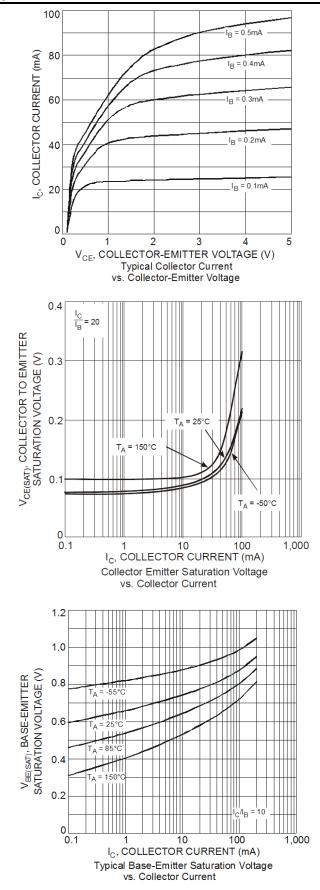
Characteristic		Symbol	Min	T.m	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	Symbol	IVIIN	Тур.	wax	Unit	Test Condition	
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	60			V	$I_{\rm C} = 50 \mu {\rm A}, I_{\rm E} = 0$	
Collector-Emitter Breakdown Voltage		V <sub>(BR)CEO</sub>	50			V	$I_{\rm C} = 1$ mA, $I_{\rm B} = 0$
Emitter-Base Breakdown Voltage		V <sub>(BR)EBO</sub>	7			V	$I_E = 50\mu A$ , $I_C = 0$
Collector Cutoff Current		ICBO			100	nA	$V_{CB} = 60V$
Emitter Cutoff Current		I <sub>EBO</sub>	_	_	100	nA	$V_{EB} = 6V$
ON CHARACTERISTICS (Note 7)							•
DC Current Gain 2DC4617Q 2DC4617R 2DC4617R 2DC4617S		h <sub>FE</sub>	120 180 270		270 390 560		$V_{CE} = 6V, I_C = 1mA$
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>			0.4	V	$I_{\rm C} = 50 {\rm mA}, I_{\rm B} = 5 {\rm mA}$	
SMALL SIGNAL CHARACTERISTICS							
Output Capacitance	C <sub>obo</sub>		2	3.5	pF	$V_{CB} = 12V, f = 1MHz, I_E = 0$	
Current Gain-Bandwidth Product	f⊤	_	140	_	MHz	$V_{CE} = 12V, I_C = 2mA,$ f = 1MHz	
Current Gain-Bandwidth Product		f⊤	_	180	_	MHz	$V_{CE} = 12V$ , $I_C = 0mA$ , f = 1MHz
Current Gain-Bandwidth Product		f⊤	_	180		MHz	$V_{CE} = 12V$ , $I_C = 2mA$ , f = 100MHz

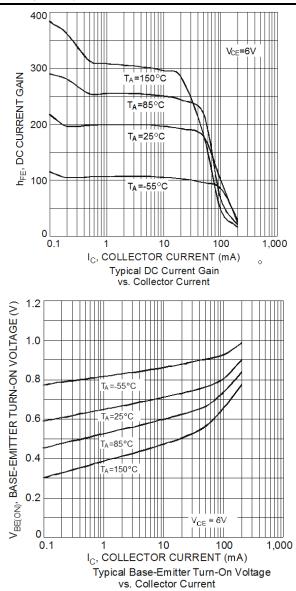
Notes: 7. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



# 2DC4617Q/R/S

# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

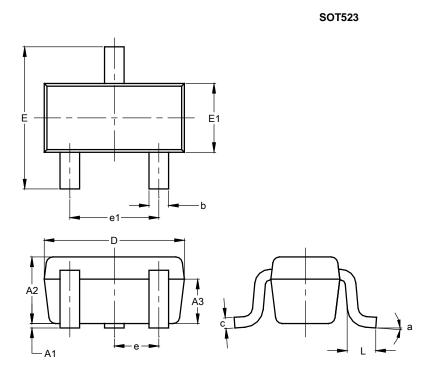






# Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

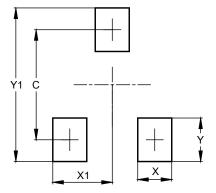


	SOT523							
Dim	Min Max Typ							
A1	0.00	0.10	0.05					
A2	0.60	0.80	0.75					
A3	0.45	0.65	0.50					
b	0.15	0.30	0.22					
С	0.10	0.20	0.12					
D	1.50	1.70	1.60					
Е	1.45	1.75	1.60					
E1	0.75	0.85	0.80					
е		0.50 BS	С					
e1	0.90	1.10	1.00					
L	0.20	0.40	0.33					
а	0°		8°					
Α	I Dimen	isions ir	n mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

# SOT523



Dimensions	Value (in mm)
С	1.29
Х	0.40
X1	0.70
Y	0.51
Y1	1.80



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